

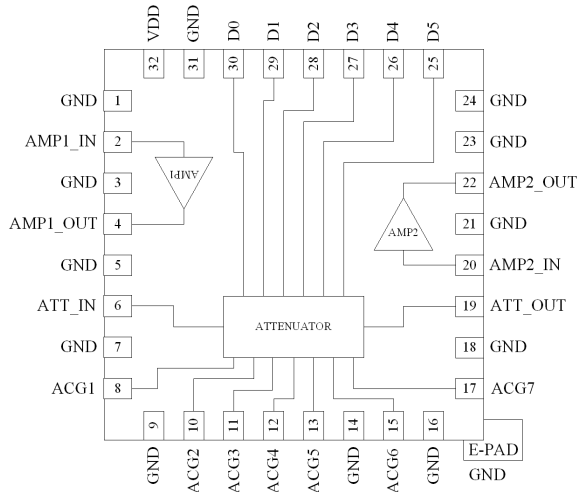


Features

- Broadband 50MHz to 1000MHz Operation
- 6-Bit Digital Step Attenuator
- Parallel Mode Gain Programming
- Max Gain=38.8dB at 140MHz
- Gain Control Range=31.5dB (0.5dB Step Size)
- High OIP3/P1dB=+42/20dBm at 140MHz
- Single +5V Supply
- 3V or 5V Logic Level Compatible
- Small 32-Pin, 5.2mmx5.2mm, MCM
- Footprint Compatible with 5mmx5mm 32-Pin QFN

Applications

- Linear IF Applications
- Cellular, 3G Infrastructure
- WiBro, WiMAX, LTE
- Microwave Radio
- High Linearity Power Control



Functional Block Diagram

RFMD's RDA2032Z is a digital controlled variable gain amplifier (DVGA) featuring high linearity over the entire gain control range. The attenuation of the 6-bit digital step attenuator is programmed with a parallel mode control interface. The RDA2032Z has two amplifier stages packaged in a small 5.2mmx5.2mm leadless laminate MCM containing plated through thermal vias for ultra low thermal resistance. The footprint for this module is directly compatible with a 5mmx5mm 32-pin QFN. This module is easy to use with no external matching components required.

Optimum Technology Matching® Applied

- | | | | |
|---|--------------------------------------|--|------------------------------------|
| <input type="checkbox"/> GaAs HBT | <input type="checkbox"/> SiGe BiCMOS | <input checked="" type="checkbox"/> GaAs pHEMT | <input type="checkbox"/> GaN HEMT |
| <input type="checkbox"/> GaAs MESFET | <input type="checkbox"/> Si BiCMOS | <input type="checkbox"/> Si CMOS | <input type="checkbox"/> BiFET HBT |
| <input checked="" type="checkbox"/> InGaP HBT | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si BJT | <input type="checkbox"/> LDMOS |

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Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	5.5	V
DC Supply Current	228	mA
Power Dissipation	1054	mW
Max Input RF Power	+24	dBm
Operating Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C
Junction Temperature (T _J)	+150	°C
ESD Rating (HBM)	500 (Class 1B)	V
Moisture Sensitivity Level (MSL)	3	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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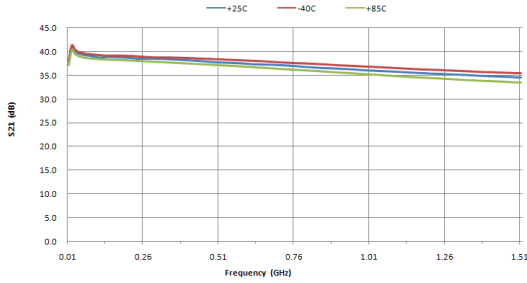
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Overall					Temp=25 °C, V _{CC} =V _{DD} =5V, V _{CTL} =TTL Logic, Tested With Evaluation Circuit
Frequency Range	50		1000	MHz	
Gain Max at 140MHz		38.8		dBm	Attenuation=0dB
Gain Control Range		31.5		dB	0.5dB step
Step Accuracy	±(0.15 + 3% attenuation setting)			dB	Major state max error up to 1000MHz
OP1dB at 140MHz		20		dBm	Attenuation=0dB
OIP3 at 140MHz		42		dBm	P _{OUT} =0dBm/tone, 1MHz spacing
Control Interface		6			Parallel mode 6-bit
Settling Time		220		ns	t _{ON} , t _{OFF} (10%/90% RF)
NF at 140MHz		3.2		dB	Attenuation=0dB
Input Return Loss at 140MHz		-30		dB	50Ω system
Output Return Loss at 140MHz		-25		dB	50Ω system
Amplifier Supply Voltage (V _{CC})	4.75	5.0	5.25	V	
Attenuator Supply Voltage (V _{DD})	3.0	5	5.25	V	
Total Supply Current	164	182	204	mA	Sum of currents from V _{DD} and V _{CC}
Thermal Resistance		39		°C/W	

Typical RF Performance at Key Operating Frequencies

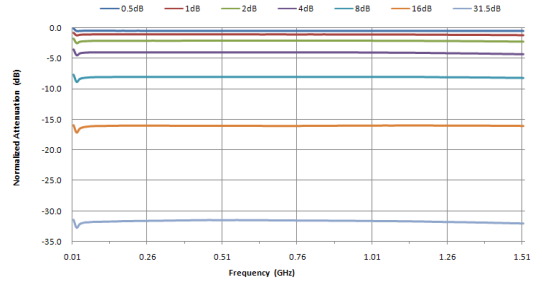
Parameter	Unit	50MHz	140MHz	280MHz	500MHz	850MHz	1000MHz
Max Small Signal Gain	dB	39.5	38.8	38.5	37.8	36.5	36.0
OP1dB	dBm	19.5	20.0	20.0	20.0	19.8	19.6
OIP3	dBm	40.0	42.0	42.0	39.5	36.0	35.0
Input Return Loss	dB	-20	-30	-20	-19	-16	-15
Output Return Loss	dB	-30	-28	-23	-20	-11.5	-10
NF	dB	3.1	3.2	3.3	3.3	3.3	3.3

Typical Performance

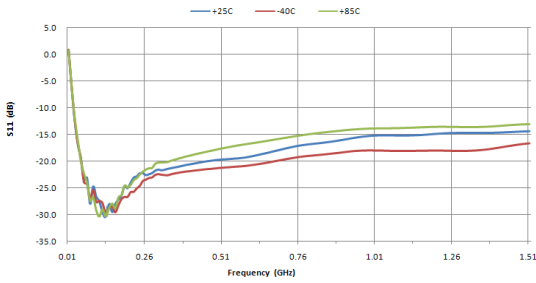
Max Gain



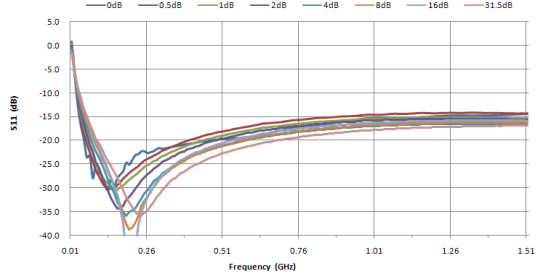
Normalized Attenuation



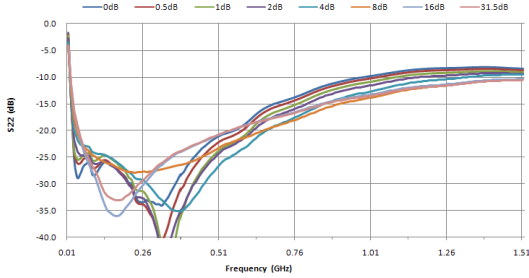
Input Return Loss



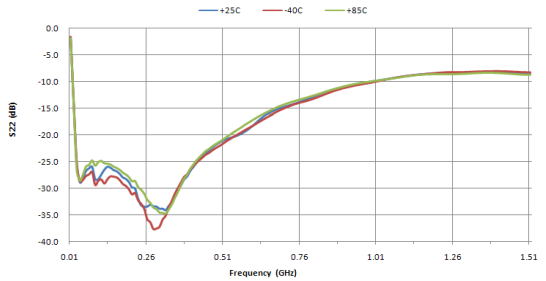
Input Return Loss at Major Gain Steps



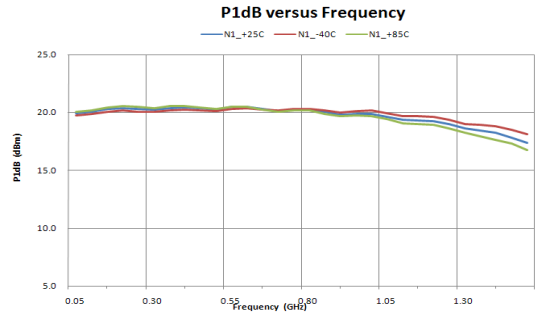
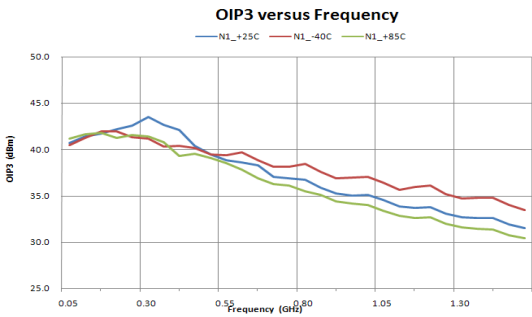
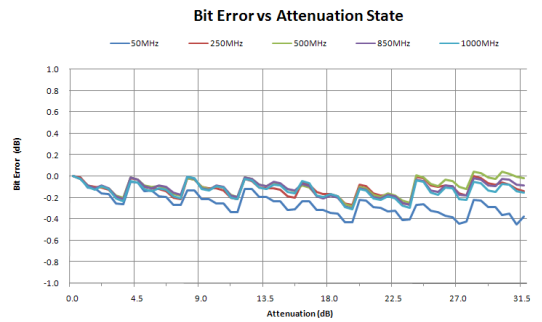
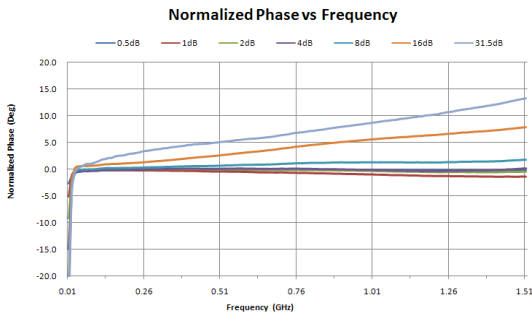
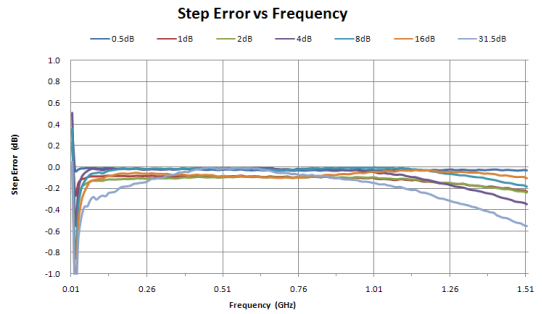
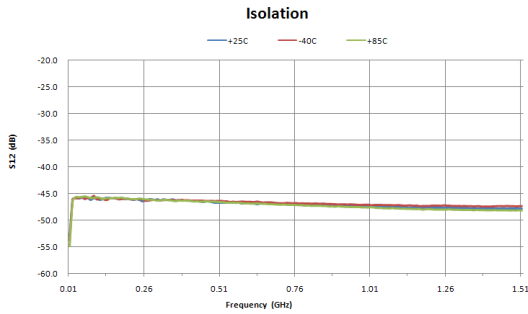
Output Return Loss at Major Gain Steps



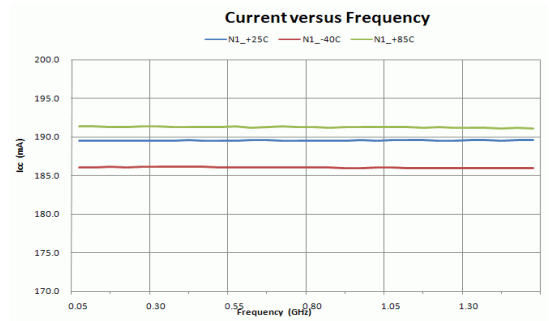
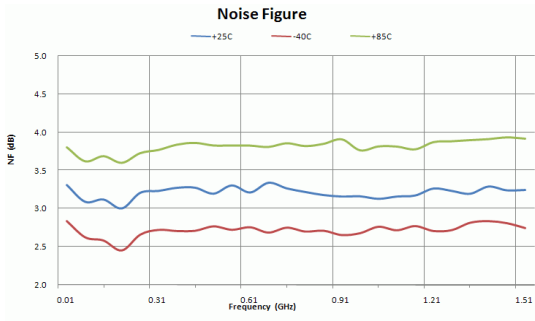
Output Return Loss



Typical Performance



Typical Performance

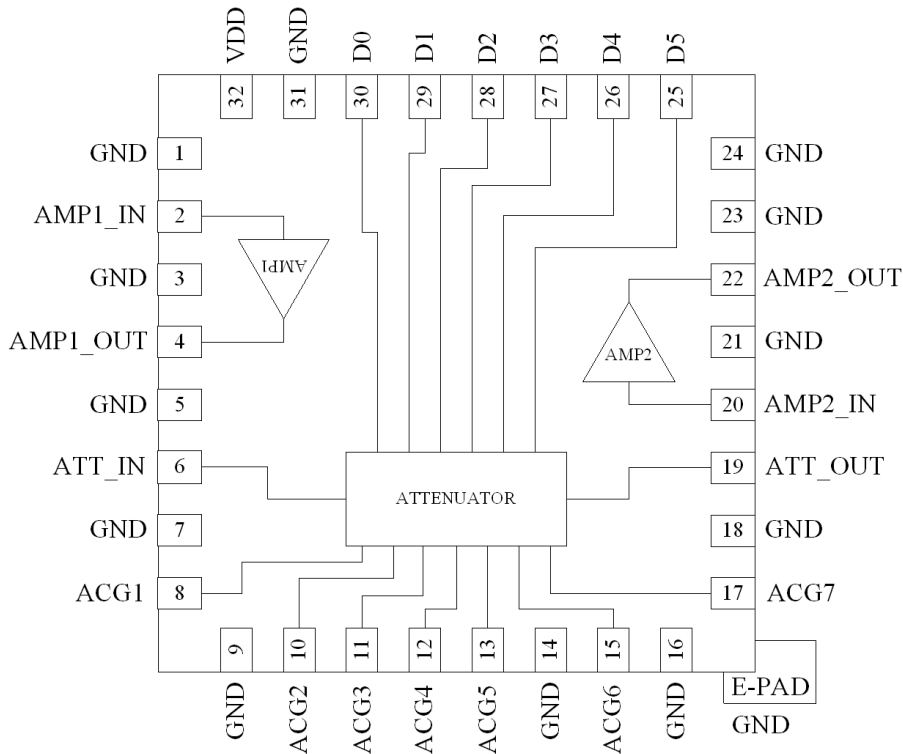


Truth Table

Control Bit						Gain Relative to Maximum Gain
D5	D4	D3	D2	D1	D0	
1	1	1	1	1	1	0dB
1	1	1	1	1	0	-0.5dB
1	1	1	1	0	1	-1dB
1	1	1	0	1	1	-2dB
1	1	0	1	1	1	-4dB
1	0	1	1	1	1	-8dB
0	1	1	1	1	1	-16dB
0	0	0	0	0	0	-31.5dB

Logic Voltage Levels		
State	V _{DD} =+3.3V	V _{DD} =+5V
Low	0V to 0.8V	0V to 0.8V
High	2.0V to V _{DD}	2.0 to V _{DD}

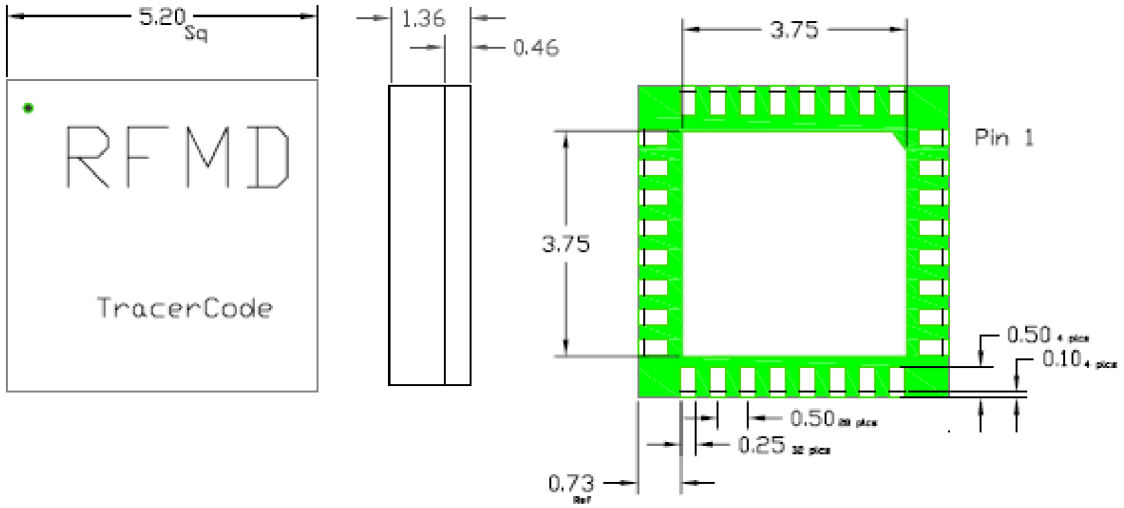
Functional Block Diagram



Pin	Function	Description
1	GND	RF/DC Ground Connection.
2	AMP1_IN	RF Amplifier 1 Input. DC block required.
3	GND	RF/DC Ground Connection.
4	AMP1_OUT	RF Amplifier 1 Output. DC block required.
5	GND	RF/DC Ground Connection.
6	ATT_IN	Digital Attenuator Input. DC block required.
7	GND	RF/DC Ground Connection.
8	ACG1	Place external capacitor to ground.
9	GND	RF/DC Ground Connection.
10	ACG2	Place external capacitor to ground.
11	ACG3	Place external capacitor to ground.
12	ACG4	Place external capacitor to ground.
13	ACG5	Place external capacitor to ground.
14	GND	RF/DC Ground Connection.
15	ACG6	Place external capacitor to ground.
16	GND	RF/DC Ground Connection.
17	ACG7	Place external capacitor to ground.
18	GND	RF/DC Ground Connection.
19	ATT_OUT	Digital Attenuator Output. DC block required.
20	AMP2_IN	RF Amplifier 2 Input. DC block required.
21	GND	RF/DC Ground Connection.
22	AMP2_OUT	RF Amplifier 2 Output. DC block required.
23	GND	RF/DC Ground Connection.
24	GND	RF/DC Ground Connection.
25	D5	Digital attenuator parallel control line: 16 dB bit.
26	D4	Digital attenuator parallel control line: 8 dB bit.
27	D3	Digital attenuator parallel control line: 4 dB bit
28	D2	Digital attenuator parallel control line: 2 dB bit.
29	D1	Digital attenuator parallel control line: 1 dB bit.
30	D0	Digital attenuator parallel control line: 0.5 dB bit.
31	GND	RF/DC Ground Connection.
32	VDD	Digital attenuator supply Voltage.

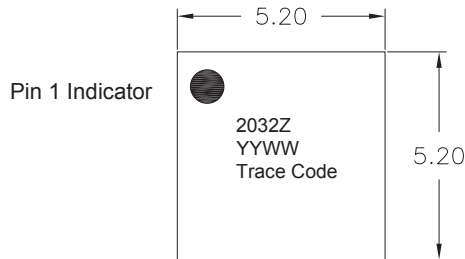
Package Drawing

5.2mmx5.2mm Laminate Module

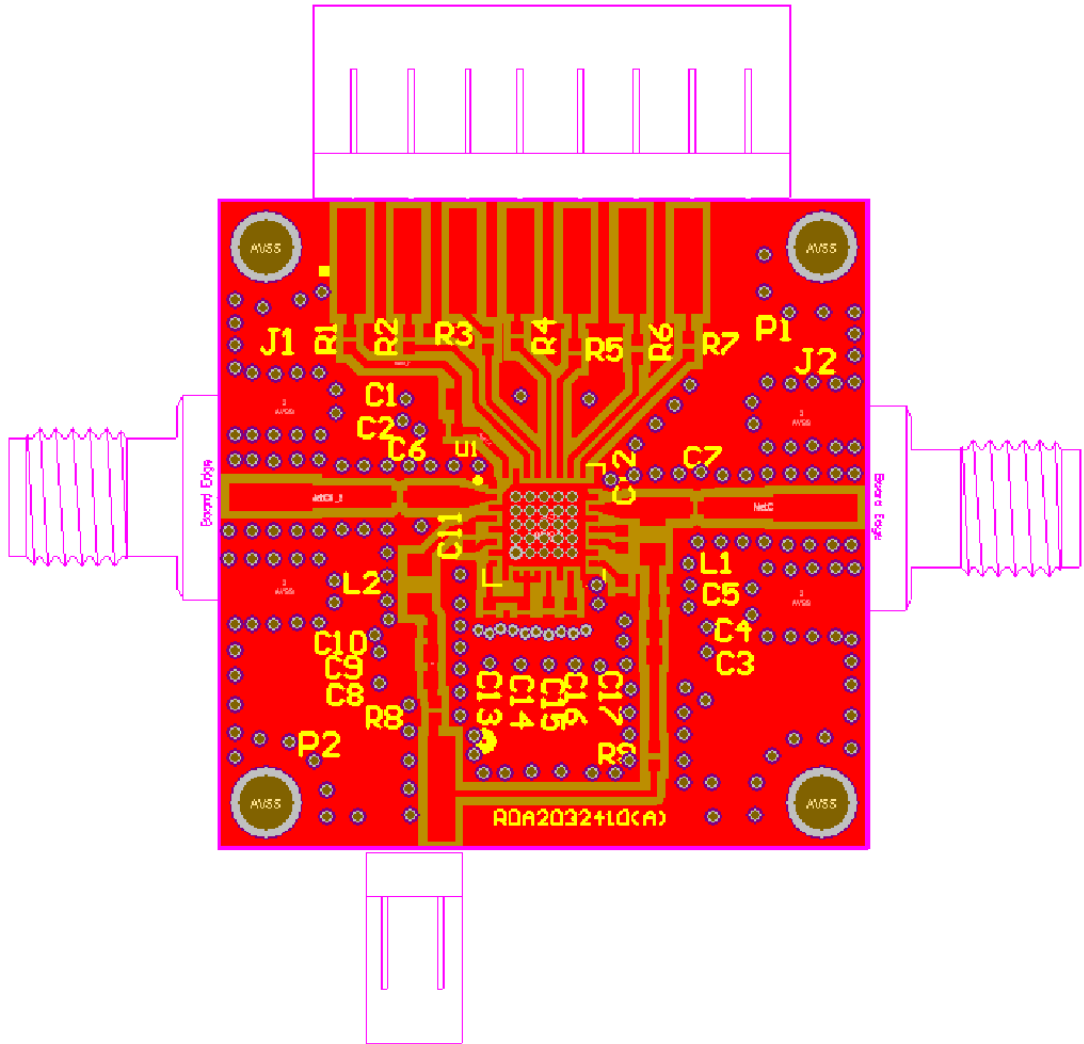


Note: Module thickness tolerance = ± 0.04 mm. Other dimension tolerances = ± 0.075 mm.

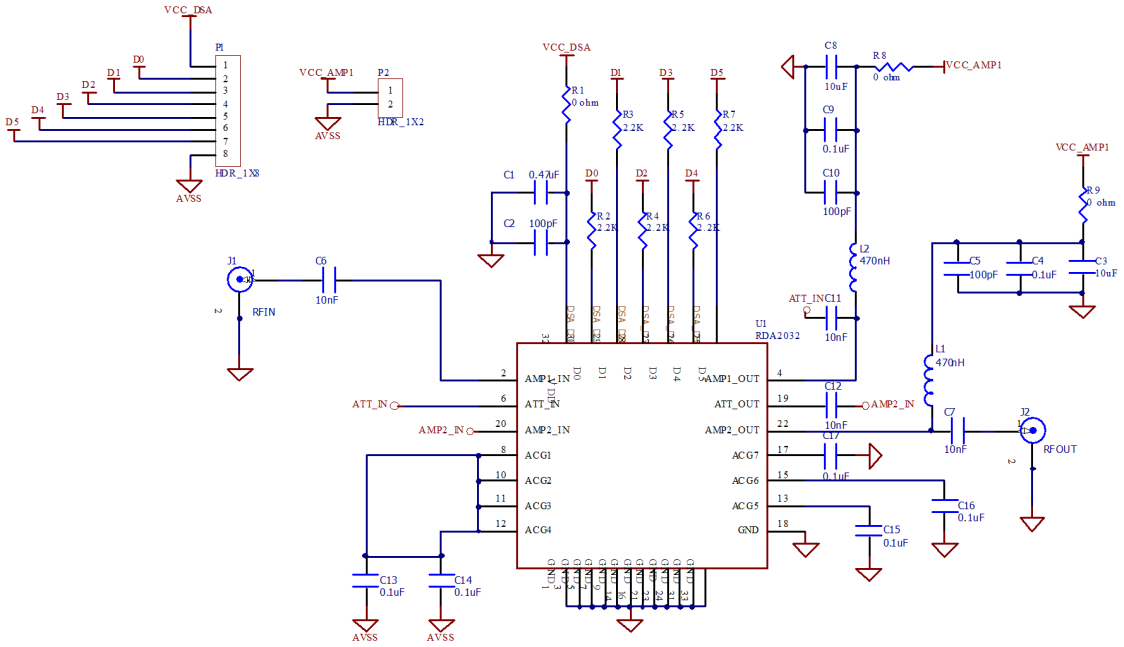
Branding Diagram



Evaluation PCB



Evaluation Board Schematic



Bill of Materials

Quantity	Description	Reference Designator	Manufacturer	Manufacturer's Part Number
1	CAP, 0.47uF, 10%, 10V, X5R, 0603	C1	Murata Electronics	GRM188R61A47K61D
2	CAP, 10uF, 20%, 6.3V, X5R, 0603	C3, C8	Murata Electronics	GRM188R60J106ME47D
2	CAP, 0.1uF, 10%, 16V, X7R, 0603	C4, C9	Murata Electronics	GRM188R71C104KA01D
3	CAP, 100pF, 5%, 50V, C0G, 0402	C2, C10, C5	Panasonic	ECJ-OEC1H101J
5	CAP, 0.1uF, 10%, 10V, X5R, 0402	C13, C14, C15, C16, C17	Taiyo Yuden	RM LMK105BJ104KV
4	CAP, 10000pF, 10%, 16V, X7R, 0402	C6, C7, C11, C12	Taiyo Yuden	RM EMK105BJ103KV-F
2	IND, 470nH, 10%, W/W, 0805	L1, L2	Coilcraft	0805LS-471XSLB
2	JMPR, 0 OHM, 0402	R1, R8, R9	Panasonic	ERJ-2GE0R00
6	RES, 2.2K, 5%, 1/16W, 0402	R2, R3, R4, R5, R6, R7	Panasonic	ERJ-2GEJ222

Ordering Information

Ordering Code	Description
RDA2032ZSQ	Sample bag with 25 pieces
RDA2032ZSR	7" Reel with 100 pieces
RDA2032ZTR7	7" Reel with 750 pieces
RDA2032ZTR13	13" Reel with 2500 pieces
RDA2032ZPCK-410	50MHz to 1000MHz PCBA with 5-piece sample bag

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[MAX2689EWS+T](#) [MAAMSS0041TR](#) [MAAM37000-A1G](#) [LTC6430AIUF-15#PBF](#) [CHA5115-QDG](#) [SMA70-2](#) [SMA4011](#) [A231](#) [HMC-](#)
[AUH232](#) [LX5511LQ](#) [LX5511LQ-TR](#) [HMC7441-SX](#) [HMC-ALH310](#)